



제 29회 한국반도체학술대회

The 29th Korean Conference on Semiconductors

2022년 1월 24일(월)~ 26일(수) | 강원도 하이원 그랜드호텔(컨벤션타워)

2022년 1월 25일(화), 10:45-12:30

Room G (스페이드 II+III, 6층)

J. Nano-Science & Technology 분과

[TG2-J] 2D Materials

좌장: 이관형 교수(서울대학교), 왕건욱 교수(고려대학교)

<p>TG2-J-1 10:45-11:00</p>	<p>Observation of Negative Differential Resistance in Ambipolar Multilayered Black Phosphorus without Heterojunctions Yeeun Kim^{1,2}, Chulmin Kim³, Takhee Lee², Gyu-Tae Kim³, and Min-Kyu Joo^{1,4} ¹Department of physics, Sookmyung Women's University, ²Department of physics and Astronomy, Seoul National University, ³School of Electrical Engineering, Korea University, ⁴Department of Applied Physics, Sookmyung Women's University</p>
<p>TG2-J-2 11:00-11:30</p>	<p>Giant 2D Single-Crystalline Metallic Nanosheets: Synthesis and Applications Tae-Wook Kim Department of Flexible and Printable Electronics, Jeonbuk National University</p>
<p>TG2-J-3 11:30-11:45</p>	<p>High-performance Field-effect-transistor based on MOCVD Grown Bismuth-oxy-chalcogenides Hyun-Jun Chai¹, Minsoo Kang¹, Hu Young Jeong², and Kibum Kang¹ ¹KAIST, ²UNIST</p>
<p>TG2-J-4 11:45-12:00</p>	<p>Carrier Transport Analysis on Hexagonal WS₂ Field Effect Transistor Jungchun Kim¹, Donghyun Kim¹, Dong Geun Park¹, Seunghee Jin¹, Seain Bang¹, Min Jung Kim¹, Seoyeon Choi¹, Kiseok Heo¹, Gwang Hwi An², Hyun Seok Lee², and Jae Woo Lee¹ ¹Department of Electronics and Information Engineering, Korea University, ²Department of Physics, Chungbuk National University</p>
<p>TG2-J-5 12:00-12:15</p>	<p>Remote Molecular Surface Charge Transfer Doping in MoS₂ Field-Effect Transistors Juntae Jang¹, Jae-Keun Kim², Jiwon Shin¹, Jaeyoung Kim¹, Kyeong-Yoon Baek¹, Jaehyoung Park¹, Keehoon Kang³, Kyungjune Cho⁴, and Takhee Lee¹ ¹Department of Physics and Astronomy, Seoul National University, ²Max-Planck Institute of Microstructure Physics, ³Department of Materials Science and Engineering, Yonsei University, ⁴Soft Hybrid Materials Research Center, KIST</p>
<p>TG2-J-6 12:15-12:30</p>	<p>Gas-Phase Alkali Metal-Assisted MOCVD Growth of 2D Transition Metal Dichalcogenides for Large-Scale Precise Nucleation Control Tae Soo Kim¹, Krishna P. Dhakal², Eunpyo Park³, Gichang Noh^{1,3}, Hyun-Jun Chai¹, Youngbum Kim², Saeyoung Oh^{5,6}, Hu Young Jeong^{5,6}, Sunghwan Bang⁴, Joon Young Kwak³, Jeongyong Kim², and Kibum Kang¹ ¹Department of Materials Science and Engineering, KAIST, ²Department of Energy Science, Sungkyunkwan University, ³Center for Electronic Materials, KIST, ⁴Materials & Production Engineering Research Institute, LG Electronics, ⁵Central Research Facilities, UNIST ⁶Department of Materials Science and Engineering, UNIST</p>